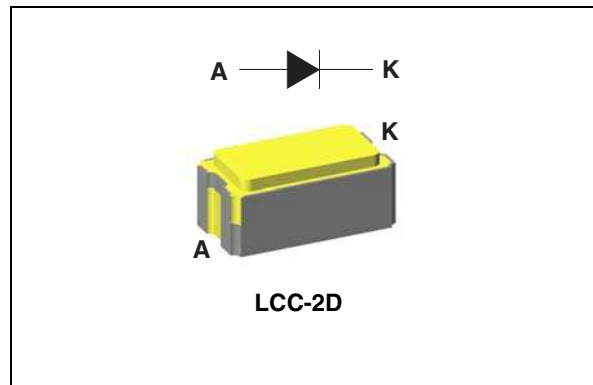


Aerospace 0.3 A - 75 V switching diode

Features

- Surface mount hermetic package
- High thermal conductivity materials
- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low forward voltage drop
- Target radiation qualification:
 - 150 krad (Si) low dose rate
 - 3 Mrad high dose rate
- Package weight: 0.12 g



Description

Packaged in LCC-2D this device is intended for use in low voltage, high frequency inverters, free wheeling, polarity protection and other aerospace applications.

Table 1. Device summary⁽¹⁾

Order code	ESCC detailed specification	Quality level	EPPL	$I_{F(AV)}$	V_{RRM}	$T_{j(max)}$	$V_F(max)$
1N6640UD1	-	Engineering model	-	0.3 A	75 V	175 °C	1.2 V
1N6640U02D	5101/027/xx	Flight part	Target				

1. Contact ST sales office for information about the specific conditions for products in die form and gold plated version.

1 Characteristics

Table 2. Absolute ratings (limiting values)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	75	V
$I_{F(RMS)}$	Forward rms current	0.5	A
$I_{F(AV)}$	Average forward rectified current ⁽¹⁾	300	mA
I_{FSM}	Forward surge current	$t_p = 8.3$ ms sinusoidal, $t_{amb} \leq 25$ °C	2 A
T_{stg}	Storage temperature range	-65 to +175	°C
T_j	Operating junction temperature range	-65 to +175	°C
T_{sol}	Maximum soldering temperature ⁽²⁾	245	°C

1. For all variants at $T_c \geq +155$ °C per diode, derate linearly to 0A at +175 °C.
2. Maximum duration 5 s. The same package must not be re-soldered until 3 minutes have elapsed.

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case ⁽¹⁾	60	°C/W
$R_{th(j-a)}$	Junction to ambient	280	

1. Package mounted on infinite heatsink.

Table 4. Static electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
$V_{BR}^{(1)}$	Breakdown voltage	$T_j = 25$ °C	$I_R = 10$ μA	75	-	-	V
$I_R^{(1)}$	Reverse current	$T_j = 25$ °C	$V_R = 50$ V	-	-	40	nA
		$T_j = 150$ °C		-	-	30	μA
$V_F^{(2)}$	Forward voltage	$T_j = 25$ °C	$I_F = 1$ mA	540	-	630	mV
		$T_j = 25$ °C	$I_F = 50$ mA	760	-	890	
		$T_j = 25$ °C	$I_F = 100$ mA	820	-	980	
		$T_j = 25$ °C	$I_F = 200$ mA	870	-	1100	
		$T_j = -55$ °C	$I_F = 200$ mA	-	-	1200	

1. Pulse test: $t_p = 10$ ms, $\delta < 2\%$
2. Pulse test: $t_p = 680$ μs, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.74 \times I_{F(AV)} + 1.00 \times I_{F(RMS)}^2$$

Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
t_{rr}	Reverse recovery time	$I_F = I_R = 10 \text{ mA}$	-	-	9	ns
		$I_F = 1 \text{ A}, V_r = 30 \text{ V}, di/dt = -15 \text{ A}/\mu\text{s}$	-	-	20	
V_{FP}	Forward recovery voltage	$I_{FM} = 200 \text{ mA}$	-	-	5	V
t_{FR}	Forward recovery time	$I_{FM} = 200 \text{ mA}$	-	-	20	ns
C_j	Diode capacitance	$V_R = 0 \text{ V}, V = 50 \text{ mV}, F = 1 \text{ MHz}$	-	-	3	pF

Figure 1. Forward voltage drop versus forward current (typical values)

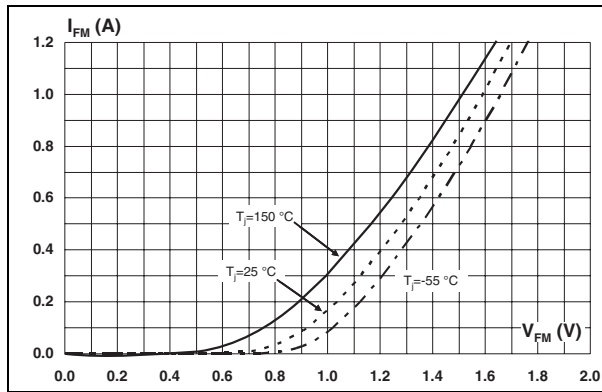


Figure 2. Forward voltage drop versus forward current (maximum values)

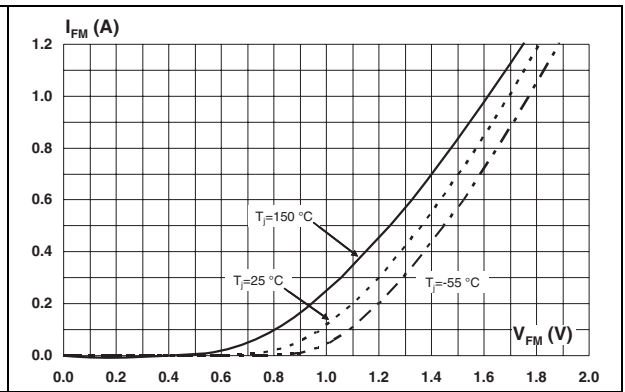


Figure 3. Reverse leakage current versus reverse voltage applied (typical values)

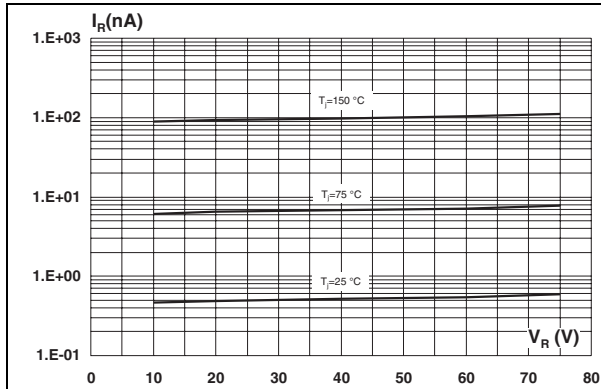


Figure 4. Relative variation of thermal impedance, junction to case, versus pulse duration

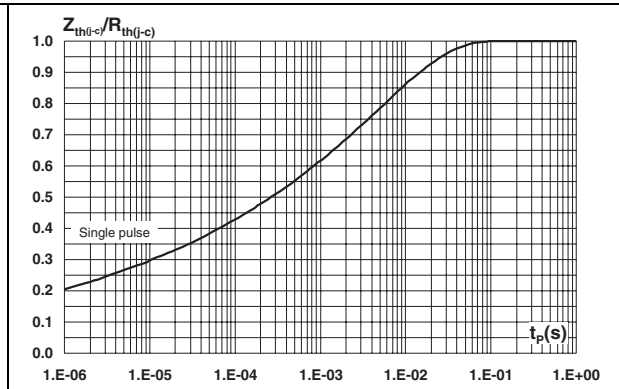
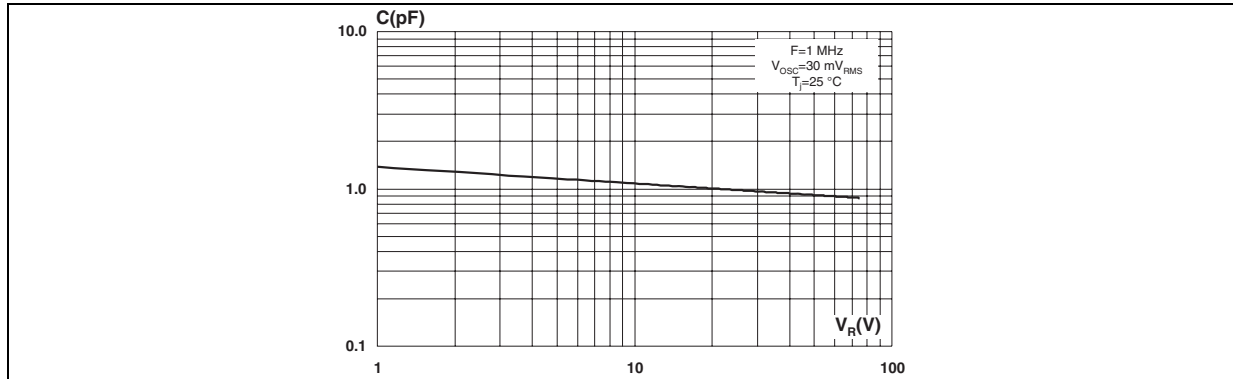


Figure 5. Junction capacitance versus reverse voltage applied (typical values)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 6. Leadless chip carrier 2 (LCC-2D) package dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A ⁽¹⁾	1.86	2.03	2.20	0.073	0.080	0.087
B	4.44	4.57	4.77	0.175	0.180	0.188
C	1.84	1.97	2.10	0.072	0.078	0.083
D	1.53	1.70	1.87	0.060	0.067	0.074
E	0.48	-	0.71	0.019	-	0.028
F	-	1.3	-	-	0.051	-
G	-	1.67	-	-	0.066	-
H	-	0.37	-	-	0.015	-
I	-	0.15	-	-	0.006	-
r1	-	0.15	-	-	0.006	-
r2	-	0.20	-	-	0.008	-

Note 1: The anode is identified by metallization in two top internal angles and the index mark.

1. Measurement prior to solder coating the mounting pads on bottom of package

3 Ordering information

Table 7. Ordering information⁽¹⁾

Order code	ESCC detailed specification	Package	Lead finish	Marking	EPPL	Weight	Packing
1N6640UD1	-	LCC-2D	Gold	40UD1	-	0.12 g	Waffle pack
1N6640U02D	5101/027/xx		Solder dip	40U02D	Target		

1. Contact ST sales office for information about the specific conditions for products in die form and gold plated version.

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
26-Mar-2010	1	First issue.
23-Sep-2011	2	Updated order codes in Table 1 and Table 7 .

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